53 (EC 201) BSEL

2017

BASIC ELECTRONICS

Full Marks: 100

Time: Three hours

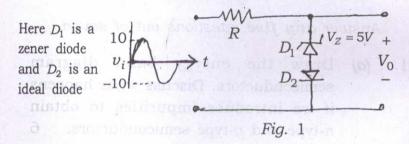
The figures in the margin indicate full marks for the questions.

Answer any five questions out of seven.

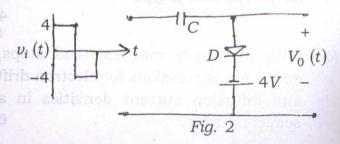
- 1. (a) Draw the energy band diagram semiconductors. Discuss what happens if we introduce impurities to obtain n-type and p-type semiconductors. 6
 - (b) State and prove the law of mass action for n-type and p-type semiconductors.

(c) With necessary mathematical steps, derive the expressions for electron drift and diffusion current densities in a semiconductor.

- (d) Show that the change in minority carrier concentration near to the depletion region depend on the magnitude of applied potential across the *p-n* junction.
- 2. (a) Draw the energy band diagram of tunnel and avalanche diodes and explain the differences in their breakdown mechanism.
 - (b) Find the output waveform of the circuit shown in Fig. 1.

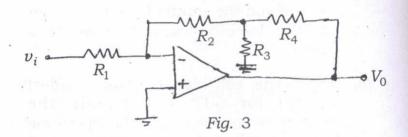


(c) Evaluate the output waveform of the circuit shown in Fig. 2.



- (d) Derive the expressions for rectification efficiency, η and ripple factor, γ at the output of a full wave rectifier.
- 3. (a) Explain why, when a BJT is biased in active mode, the collector current depends on the emitter current and not on the base-collector reverse bias voltage?
 - (b) Draw the self-bias (voltage divider) circuit for BJT and explain the procedure to determine the operating point (Q-point) of the transistor. 5
 - (c) Draw the schematic diagram of an n-channel JFET and distinguish its working in ohmic and saturation region of operation.
 - (d) Derive the expression for drain current, I_D in an n-channel MOSFET when $V_{DS} << V_{GS} V_T$. Here V_T is the threshold voltage.
- 4. (a) Draw the circuit diagram of a Weinbridge oscillator and find out the condition under which it will give sustained oscillatory output.

- (b) Discuss the desirable characteristics of any good voltage amplifier. 4
- (c) For the circuit shown in Fig. 3, evaluate the expression for the output voltage, V_0 .



5. (a) Evaluate the following:

(i)
$$(323)_8 + (425)_8 = ()_8$$

(ii)
$$(43)_{10} = ()_{16}$$

(iii)
$$(0.25)_{10} = ()_2$$

(iv)
$$(1217)_8 = ()_{16}$$

(b) Simplify the Boolean function

$$F(w, x, y, z) = \Sigma(0, 1, 2, 4, 5, 6, 8, 9, 12, 13, 14)$$

- (c) Implement the Boolean function, F = AB + CD + E using NAND gates alone.
- (d) Design a 4-bit adder-subtractor circuit and explain its working.
- (e) Implement the Boolean function, $F(A, BC) = \sum (1, 3, 5, 6)$ using a multiplexer.
- 6. (a) What are sequential circuits? Explain the working of a clocked master-slave JK flip-flop with the help of a neat circuit diagram.
 - (b) Explain the working of a permanent magnet moving coil (PMMC) meter. Explain how one can design a PMMC based voltmeter, given its internal resistance $R_m = 100\Omega$ and full-scale deflection current $I_f = 100\mu A$, to measure voltages in three different ranges, viz 0-1V, 0-10V and 0-100V.
- 7. (a) Draw a neat diagram of Cathode Ray Tube (CRT) and explain its working.

- (b) Draw the circuit diagram for generating the sweep waveform (Saw-tooth waveform) of different slope for the input of X-deflection plates of the CRO. Explain its working.
- (c) With a neat schematic diagrama explain the working principle of LCD display.

(b) Explain the worland of he comment

registance AT = 100.0 and full-scale

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